## NSN 5961-01-273-5154

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-273-5154 **Inclosure Material:** Glass **Overall Length:** Between 0.085 inches and 0.120 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.050 inches and 0.075 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-34 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 reverse voltage, dc and 30.0 breakdown voltage, dc **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset and 50.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-emitter peak **Capacitance Rating In Picofarads:** Between 6.0 and 31.9 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No